SiC Power Module

BSM450D12P4G102

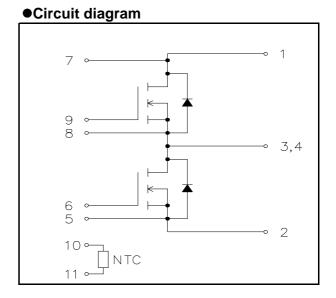
Datasheet

Application

- · Motor drive
- · Inverter, Converter
- · Photovoltaics, wind power generation.
- · Induction heating equipment.

Features

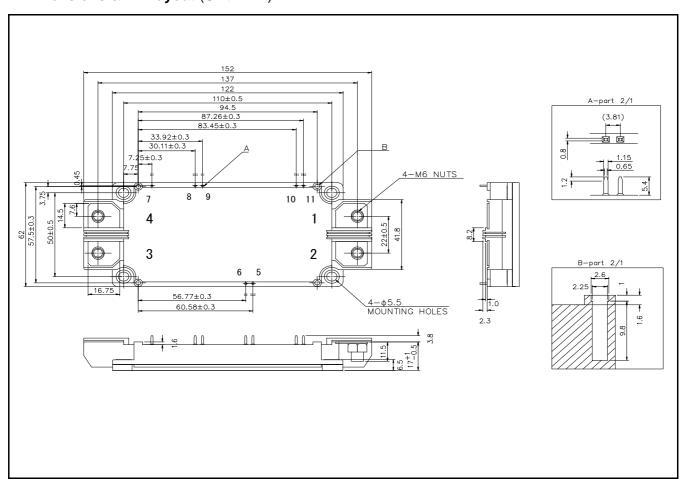
- 1) Low surge, low switching loss.
- 2) High-speed switching possible.
- 3) Reduced temperature dependence.



●Construction

This product is a half bridge module consisting of SiC-UMOSFET from ROHM.

● Dimensions & Pin layout (Unit : mm)



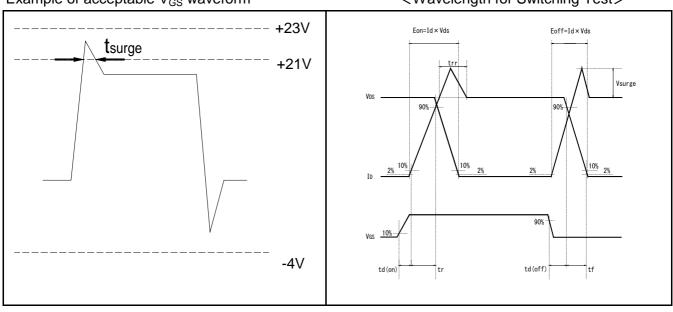
● Absolute maximum ratings (T_i = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit	
Drain - Source Voltage	Source Voltage V _{DSS} G-S short		1200		
Gate - Source Voltage (+)	V_{GSS}	D-S short	21	V	
Gate - Source Voltage (-)	V_{GSS}	D-S short	-4		
G - S Voltage (t _{surge} <300nsec)	V _{GSSsurge}	D-S short Note 1)	-4 to 23		
Drain Current	I _D	DC(Tc=60°C) V _{GS} =18V	447	-	
Drain Current Note 2)	I _{DRM}	Pulse (Tc = 60° C) 1ms V _{GS} = $18V$ _{Note 3)}	900		
Source Current Note 2)	Is	DC(Tc=60°C) V _{GS} =18V	447	Α	
	I _{SRM}	Pulse (Tc = 60° C) 1ms V _{GS} = 18 V _{Note 3)}	900		
	I _{SRM}	Pulse (Tc = 60° C) 1.5µs V _{GS} =0V _{Note 3) 4)}	900		
Total Power Dissipation Note 5)	Ptot	Tc = 25°C	1450	W	
Max Junction Temperature	Tjmax		175		
Junction Temperature	Tjop		-40 to 150	°C	
Storage Temperature	Tstg		-40 to 125		
Isolation Voltage	Visol	Terminals to baseplate f = 60Hz AC 1 min.	2500	Vrms	
Mounting Torque		Main Terminals : M6 screw	4.5	N·m	
Mounting Torque	-	Mounting to heat sink M5 screw	3.5		

- Note 1) Please note especially when using driver source that V_{GSSsurge} must be in the range of absolute maximum rating.
- Note 2) Case temperature (Tc) is defined on the surface of base plate just under the chips.
- Note 3) Repetition rate should be kept within the range where temperature rise if die should not exceed Tjmax.
- Note 4) Repititive pulse, PW \leq 1.5 μ s, Duty cycle \leq 5%
- Note 5) Tj is less than 175°C.

Example of acceptable V_{GS} waveform

<Wavelength for Switching Test>



●Electrical characteristics (T_i=25°C)

Parameter	Symbol	Conditions			Ratings Min. Typ. Max.		
1 arameter Symbo		Conditions			Тур.	Max.	Unit
On-state static	Vos(on)		Tj=25°C	_	1.5	1.8	V
Drain-Source		I_{D} =450A, V_{GS} =18V	Tj=125°C	_	2.2		
Voltage			Tj=150°C	_	2.5	3.0	
Drain Cutoff Current	IDSS	V _{DS} =1200V, V _{GS} =0V		_	_	1	μΑ
Souce-Drain Voltage	Vsp	Tj=25°C		_	4.1	_	
		· · · · · · · · · · · · · · · · ·	Tj=125°C	_	4.4	_	V
			Tj=150°C	_	4.5	_	
		Vgs=18V, Is=450A	Tj=25°C	_	1.4	_	
			Tj=125°C	_	2.1	_	
			Tj=150°C	_	2.4	_	
Gate-Source Threshold Voltage	Vgs(th)	VDS=10V, ID=218.4mA _{Not}	2.8	_	4.8	V	
Gate-Source	lgss	Vgs=21V, Vds=0V			_	0.5	μA
Leak Current		Vgs=-4V, Vds=0V			_	_	
Switching Characteristics	td(on)	Vgs(on)=18V, Vgs(off)=0V			100	_	ns
	tr	Vps=600V Ip=450A			80	_	
	trr				30	_	
	td (off)	Rg(on)=3.9 ohm, Rg(off)=3.9 ohm Inductive load		_	430	_	
	tf			_	90	_	
Input Capacitance	Ciss	V _{DS} =10V, V _{GS} =0V, 200kHz		_	44	_	nF
Gate Registance	RGint	Tj=25°C		_	0.17	_	Ω
NTC Rated Resistance	R ₂₅			_	5.0	_	kΩ
NTC B Value	B _{25/50}			_	3370	_	K
Stray Inductance	Ls			_	14.5	_	nΗ
Creepage Distance	-	Terminal to heat sink		_	16.7	_	mm
		Terminal to terminal		_	16.7	_	mm
Clearance Distance	-	Terminal to heat sink		_	12.0	_	mm
		Terminal to terminal		_	11.0	_	mm
Junction-to -Case Thermal Resistance	Rth(j-c)	UMOSFET(1/2 module) Note 7)			_	102	°C/kW
Case-to -heat sink Thermal Resistance	Rth(c-f)	Case to heat sink, per 1 module. Thermal grease applied. Note 8)			15	_	C/KVV

- Note 6) Tested after applying $V_{GS} = 21V$ for 100ms.
- Note 7) Measurement of Tc is to be done at the point just under the chip.
- Note 8) Typical value is measured by using thermally conductive grease of $\lambda=0.9W/(m\cdot K)$.
- Note 9) SiC devices have lower short cuicuit withstand capability due to high current density. Please be advised to pay careful attention to short cuicuit accident and try to adjust protection time to shutdown them as short as possible.
- Note 10) If the Product is used beyond absolute maximum ratings defined in the Specifications, as its internal structure may be dameged, please replace such Product with a new one.

Fig.1 Output characteristic 25°C (TYP)

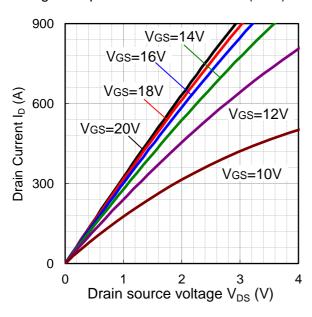


Fig.2 Drain source voltage characteristic (TYP)

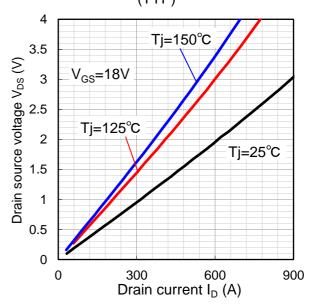


Fig.3 Drain source voltage characteristic 25°C (TYP)

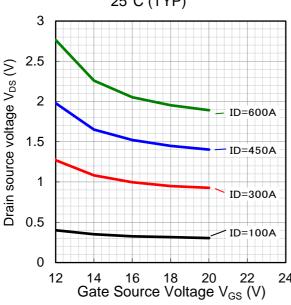


Fig.4 Ron vs Tj characteristic (TYP)

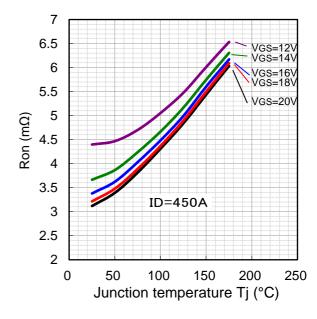


Fig.5 Forward characteristic of Diode (TYP)

1000

V_{GS}=18V

V_{GS}=0V

Tj=150°C

Tj=125°C

0.1

0

1

2

3

4

Source drain voltage V_{SD} (V)

Fig.6 Forward characteristic of Diode (TYP)

900

Tj=150°C

Tj=25°C

V_{GS}=18V

Tj=125°C

V_{GS}=0V

O

1 2 3 4 5

Source drain voltage V_{SD} (V)

Fig.7 Drain Current vs Gate Voltage (TYP)

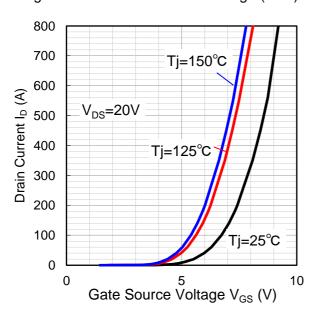


Fig.8 Drain Current vs Gate Voltage (TYP)

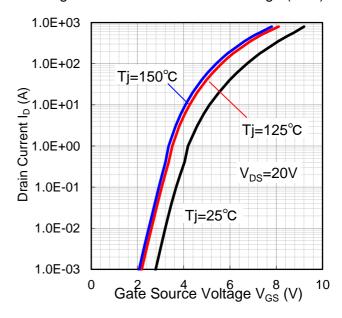


Fig.9 Switching time vs drain current at 25°C (TYP)

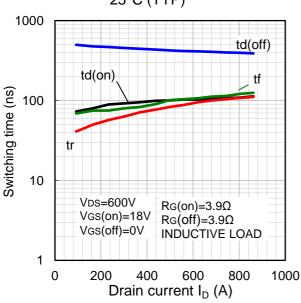


Fig.10 Switching time vs drain current at 125°C (TYP)

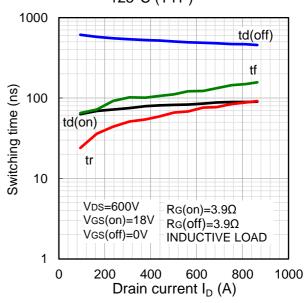


Fig.11 Switching time vs drain current at 150°C (TYP)

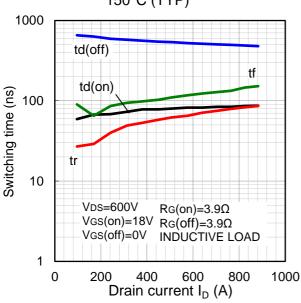


Fig.12 Switching loss vs drain current at 25°C (TYP)

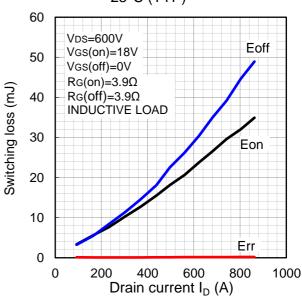


Fig.13 Switching loss vs drain current at 125°C (TYP)

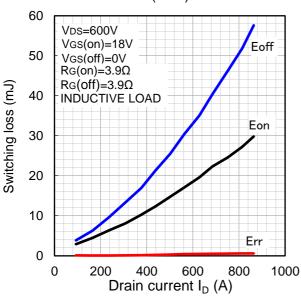


Fig.14 Switching loss vs drain current at 150°C (TYP)

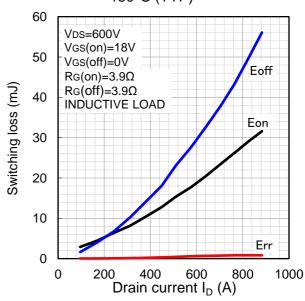


Fig.15 Recovery characteristic vs drain current at 25°C (TYP)

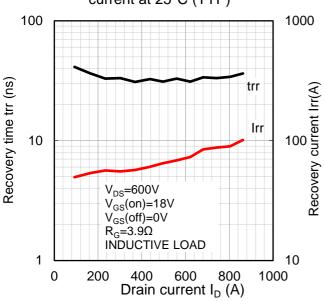


Fig.16 Recovery characteristic vs drain current at 125°C (TYP)

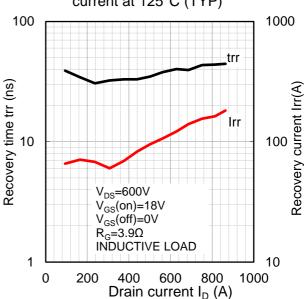


Fig.17 Recovery characteristic vs drain current at 150°C (TYP) 100 1000 trr Recovery time trr (ns) Recovery current Irr(A) Irr 10 100 V_{DS}=600V $V_{GS}(on)=18V$ $V_{GS}(off)=0V$ $R_G=3.9\Omega$ INDUCTIVE LOAD 1 10 0 200 400 600 800 1000 Drain current I_D (A)

at 25°C (TYP) 10000 V_{DS}=600V I_D=450A $V_{GS}(on)=18V$ V_{GS}(off)=0V INDUCTIVE LOAD Switching time (ns) 001 000 td(off) td(on) tf 10 1 10 Gate resistance $R_G(\Omega)$

Fig.18 Switching time vs gate resistance

at 125°C (TYP) 10000 V_{DS}=600V I_D=450A ∨ั_{GS}(on)=18V V_{GS}(off)=0V Switching time (ns) 000 INDUCTIVE LOAD td(off) td(on) 10

Gate resistance $R_G(\Omega)$

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Fig.19 Switching time vs gate resistance

at 150°C (TYP) 10000 V_{DS}=600V $V_{\rm DS}$ =000 V ID=450A V $V_{\rm GS}$ (on)=18V V $V_{\rm GS}$ (off)=0V INDUCTIVE LOAD Switching time (ns) 000 td(off) td(on) 10 1 10 Gate resistance $R_G(\Omega)$

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Fig.20 Switching time vs gate resistance

10

Fig.21 Switching loss vs gate resistance at 25°C (TYP)

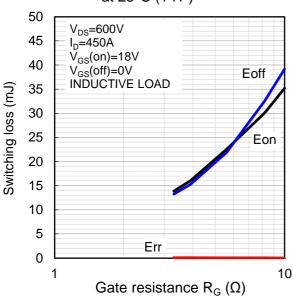


Fig.22 Switching loss vs gate resistance at 125°C (TYP)

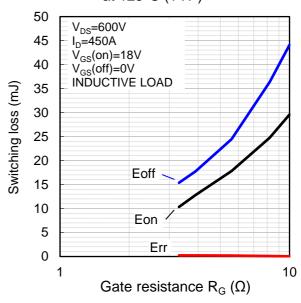
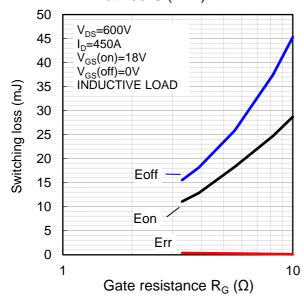
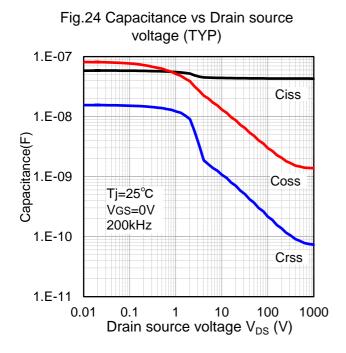


Fig.23 Switching loss vs gate resistance at 150°C (TYP)



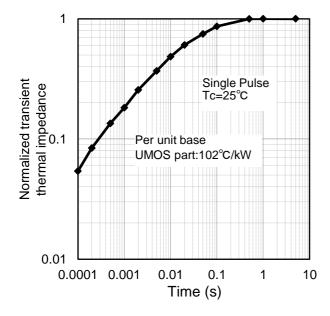


25 (N) 20 (N) 20

Gate charge Q_G (nC)

Fig.25 Gate charge characteristic (TYP)

Fig.26 Transient thermal impedance (TYP)



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